## NSN 5962-01-386-3605

Memory Microcircuit - Page 1 of 1

**Fiig:** A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-386-3605

| Maximum Power Dissipation Rating:  |
|--|
| 500.0 milliwatts   |
| Operating Tempurature Range:   |
| -55.0/+125.0 degrees celsius   |
| Storage Tempurature Range:   |
| -65.0/+150.0 degrees celsius   |
| End Application:   |
| Hsvd ac-130u e/i fscm 43999  |
| Features Provided:   |
| Electrostatic sensitive and programmed and ultraviolet erasable  |
| Inclosure Configuration:   |
| Dual-in-line   |
| Case Outline Source And Designator:  |
| D-10 mil-m-38510   |
| Voltage Rating And Type Per Characteristic:  |
| 4.5 volts applied and 5.5 volts applied  |
| Time Rating Per Chacteristic:  |
| 200.00 nanoseconds access  |
| Memory Device Type:  |
| Eprom  |
| Test Data Document:  |
| 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification |
| format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain          |
| environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883      |
| standard (includes industry or association standards, individual manufactureer standards, etc.).   |
| Terminal Type And Quantity:  |
| 28 printed circuit   |
| Departure From Cited Designator:   |
| Programmed per: es 1671  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
| <br>   |
| Demilitarization:  |
| Ves - demil/mli  |